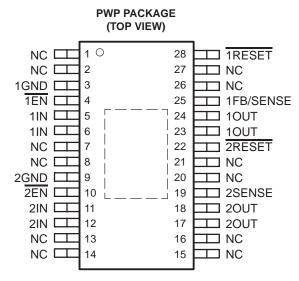
- Dual Output Voltages for Split-Supply Applications
- 3.3-V/Adjustable Output, 3.3 V/1.8 V, and 3.3 V/2.5
- Dropout Voltage < 80 mV Max at I_O = 100 mA (3.3-V option)
- Low Quiescent Current, Independent of Load ... 340 μA Typ Per Regulator
- Ultra-Low-Current Sleep State . . . 2 µA Max
- Dual Active-Low Reset Signals with 200-ms Pulse Width
- Output Current Range of 0 mA to 750 mA Per Regulator
- 28-Pin PowerPAD[™] TSSOP Package



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description

NC - No internal connection

The TPS73HD3xx family of dual voltage regulators offers very low dropout voltages and dual outputs in a compact package. Designed primarily for DSP applications, these devices can be used in any mixed-output voltage application with each regulator supporting up to 750 mA. Output current can be allocated as desired between the two regulators and used to power many of todays DSPs. Low quiescent current and very low dropout voltage assure maximum power usage in battery-powered applications. Texas Instruments PowerPAD TSSOP package allows use of these devices with any voltage/current combination within the range of the listed specifications without thermal problems, provided proper device mounting procedures are followed. Separate inputs allow the designer to configure the source power as desired. Dual active-low reset signals allow resetting of core-logic and I/O separately. Remote sense/feedback terminals provide regulation at the load. The TPS73HD3xx are available in 28-pin PowerPAD TSSOP. They operate over a free-air temperature range of -40° C to 125° C.

TA	REGULATOR 1 V _O (V)	REGULATOR 2 V _O (V)	TSSOP (PWP)
	Adj (1.2 – 9.75 V)	3.3 V	TPS73HD301PWPR
–40°C to 125°C	1.8 V	3.3 V	TPS73HD318PWPR
	2.5 V	3.3 V	TPS73HD325PWPR

AVAILABLE OPTIONS



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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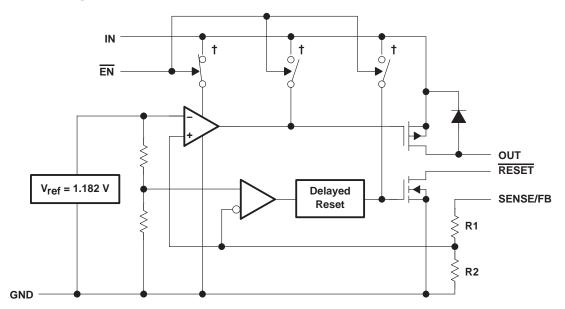
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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functional block diagram



[†] Switch positions shown with \overline{EN} low (active).

OUTPUT VOLTAGE	R1	R2	UNIT
Adjustable	0	~	Ω
1.8 V	122	233	kΩ
2.5 V	260	233	kΩ
3.3 V	420	233	kΩ

Terminal Functions

TERM	IINAL		
NAME	NO.	1/0	DESCRIPTION
NC	1, 2, 7, 8, 13–16, 20, 21, 26, 27		No connection
1GND	3		Regulator #1 ground
1EN	4	Ι	Regulator #1 enable, low = enable
1IN	5, 6	I	Regulator #1 input supply voltage
2GND	9		Regulator #2 ground
2EN	10	I	Regulator #2 enable, low = enable
2IN	11, 12	I	Regulator #2 input supply voltage
20UT	17, 18	0	Regulator #2 output voltage
2SENSE	19	I	Regulator #2 output voltage sense (fixed output)
2RESET	22	0	Regulator #2 reset signal, low = reset
10UT	23, 24	0	Regulator #1 output voltage
1FB/SENSE	25	Ι	Regulator #1 output voltage feedback (adjustable output)
1RESET	28	0	Regulator #1 reset signal, low = reset



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Input voltage range, VI (xIN, XRESET, xSENSE, XEN)	–0.3 V to 11 V
Differential input voltage, VID (1GND to 2GND)	
Output current, I _O (1OUT, 2OUT)	
Continuous total power dissipation	
Operating free-air temperature range, T _A	–40°C to 125°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 1	0 seconds 260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTE 1: All voltages are with respect to GND.

T_A < 25°C AIR FLOW DERATING FACTOR T_A = 70°C T_A = 85°C PACKAGE **POWER RATING** POWER RATING POWER RATING (CFM) ABOVE T_A = 25°C 2.9 W 23.5 mW/°C 0 1.9 W 1.5 W PWP[‡] 300 4.3 W 34.6 mW/°C 2.8 W 2.2 W 0 3 W 23.8 mW/°C 1.9 W 1.5 W **PWP**§ 300 7.2 W 57.9 mW/°C 4.6 W 3.8 W

DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURES[‡]

[‡] This parameter is measured with the recommended copper heat sink pattern on a 1-layer PCB, 5-in \times 5-in PCB, 1 oz. copper, 2-in \times 2-in coverage (4 in²).

§ This parameter is measured with the recommended copper heat sink pattern on a 8-layer PCB, 1.5-in × 2-in PCB, 1 oz. copper with layers 1, 2, 4, 5, 7, and 8 at 5% coverage (0.9 in²) and layers 3 and 6 at 100% coverage (6 in²).

recommended operating conditions

		MIN	MAX	UNIT
Input voltage, VI [†]	Adjustable output (regulator #1)	2.97	10	V
Input voltage, V _I †	3.3–V output (regulator #2)	3.97	10	V
High-level input voltage a	t EN, VIH	2		V
Low-level input voltage at	EN, VIL		0.5	V
Total output current range	(per regulator), I _O	0	750	mA
Operating virtual junction	temperature range, TJ	-40	125	°C

[†] Minimum input voltage defined in the recommended operating conditions is the maximum specified output voltage plus dropout voltage, V_{DO}, at the maximum specified load range (750 mA). Since dropout voltage is a function of output current, the usable range can be extended for lighter loads. To calculate the minimum input voltage for the maximum load current used in a given application, use the following equation:

 $V_{I(min)} = V_{O(max)} + V_{DO(max load)}$

Because regulator 1 of the TPS373HD301 is programmable, $r_{DS(on)}$ should be used to calculate V_{DO} before applying the above equation. The equation for calculating V_{DO} from $r_{DS(on)}$ is given in Note 3 in the TPS73HD301 electrical characteristics table. The minimum value of 3.5 V is the absolute lower limit for the recommended input voltage range for the TPS73HD301. With 2.97-V input voltage, the LDO may be in dropout and will not meet the 3% regulator output or 750-mA load current specification.



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electrical characteristics, V_{I(IN)} = 4.3 V, I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 µF/CSR[‡] = 1 Ω , SENSE/FB shorted to OUT (unless otherwise noted)

	PARAMETER	TEST CONDITIONS§	Тj	MIN	TYP	MAX	UNIT
	Quiescent surrent (active mode) apph regulator	$\overline{EN} \le 0.5 \text{ V}, \\ 0 \text{ mA} \le I_{O} \le 750 \text{ mA},$	25°C		340	415	
	Quiescent current (active mode), each regulator	See NOTE 2	–40°C to 125°C			550	μA
1	Supply surrent (standby mode) and regulator	$\overline{EN} = V_{I},$	25°C		0.01	0.5	
ICC	Supply current (standby mode), each regulator	NOTE 2	-40° C to 125° C			2	μA
1.	Output ourrent limit each regulator		25°C	0.8	1.2	2	^
10	Output current limit, each regulator	$V_{O} = 0$, $V_{I} = 10 V$	–40°C to 125°C			2	A
L.		$\overline{EN} = V_{I},$	25°C		0.01	0.5	
l _{lkg}	Pass-element leakage current (standby mode)	See NOTE 2	$-40^{\circ}C$ to $125^{\circ}C$			1	μA
	Output voltage temperature coefficient		–40°C to 125°C		61	75	ppm/°C
	Thermal shutdown junction temperature				165		°C
	Logic high (FN) (standby made)	$2.5 V \le V_{I} \le 6 V_{s}$	–40°C to 125°C	2			v
	Logic high (EN) (standby mode)	$6 \ V \leq V_{I} \leq 10 \ V$	-40°C 10 125°C	2.7			v
	Laria laux (FNI) (active manda)	See NOTE 2	25°C			0.5	v
	Logic low (EN) (active mode)	See NOTE 2	-40° C to 125° C			0.5	V
V _{hys}	Hysteresis voltage (EN)		25°C		50		mV
			25°C	-0.5	0.001	0.5	•
II	Input current (EN)	$0 V \le V_I \le 10 V$	–40°C to 125°C	-0.5		0.5	μA
	Minimum input voltage, for estive need element		25°C		2.05	2.5	v
	Minimum input voltage, for active pass element		-40°C to 125°C			2.5	v
			25°C		1	1.5	v
	Minimum input voltage, for valid RESET	$I_{O(RESET)} = -300 \mu A$	-40°C to 125°C			1.9	v v

⁺ CSR (compensation series resistance) refers to the total series resistance, including the equivalent series resistance (ESR) of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.

§ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

NOTE 2: Minimum input voltage is 3.5V or Vo(typ) + 1V whichever is greater.

The minimum value of 3.5 V is the absolute lower limit for the recommended input voltage range for the TPS73HD301.



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electrical characteristics, $V_{I(IN)}$ = 4.3 V, I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , SENSE/FB shorted to OUT (unless otherwise noted) (continued)

adjustable regulator

	PARAMETER	TEST CONDI	tions‡	Тј	MIN	TYP	MAX	UNIT
		$5 \text{ mA} \le I_{O} \le 750 \text{ mA},$		25°C		1.182		
	Reference voltage (1FB)	See NOTE 2		-40°C to 125°C	1.147		1.217	V
	Reference voltage temperature coef- ficient			-40°C to 125°C		61	75	ppm/°C
		50 μ A ≤ I _O ≤ 750 mA,		25°C		0.52	1	
	Pass-element series resistance (see	See NOTE 2		-40°C to 125°C			1	
	Note 3)	V _I = 3.9 V, 50 μA s	≤ I _O ≤ 750 mA	25°C		0.32		Ω
		V _I = 5.9 V, 50 μA s	≤ I _O ≤ 750 mA	25°C		0.23		
	Input regulation	V_{I} = 3.5 V, 50 μ A \leq	l _O ≤ 750 mA	25°C		3		mV
	2	$I_{O} = 5 \text{ mA to } 750 \text{ mA},$ See NOTE 2		25°C		7		mV
	Output regulation	$I_{O} = 50 \ \mu A \text{ to } 750 \ m A,$ See NOTE 2		25°C		10		mV
		f = 120 Hz,	I _O = 50 μA	25°C		59		
	Ripple rejection	f = 120 Hz,	I _O = 500 mA	25°C		54		dB
	Output noise-spectral density	f = 120 Hz		25°C		2		mV/√Hz
			$C_L = 4.7 \ \mu F$	25°C		95		
	Output noise voltage	10 Hz \leq f \leq 100 kHz, CSR = 1 Ω	$C_L = 10 \ \mu F$	25°C		89		μV/rms
		C3R = 1 12	$C_L = 100 \mu\text{F}$	25°C		74		
V(TO)	Trip-threshold voltage ($\overline{RESET})^{\S}$	VO(FB) decreasing	•	-40°C to 125°C	1.101		1.145	V
V _{hys}	Hysteresis voltage (RESET)§	Measured at VO(ER)		25°C		12		mV
	2	, <i>,</i> , ,		25°C		0.1	0.4	
VOL	Low-level output voltage (RESET)§	V _I = 2.13 V, I _{O(RE}	ESET) = 400 μA	-40°C to 125°C			0.4	V
				25°C	-10	0.1	10	
l	Input current (1FB)			-40°C to 125°C	-20		20	nA

[†] CSR (compensation series resistance) refers to the total series resistance, including the equivalent series resistance (ESR) of the capacitor, any series resistance added externally, and PWB trace resistance to C₁.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Output voltage programmed to 2.5 V with closed-loop configuration (see application information)

NOTE 3: To calculate dropout voltage, use equation:

$$I_{\rm DO} = I_{\rm O} \times r_{\rm DS(ON)}$$

 $r_{DS(ON)}$ is a function of both output current and input voltage. This parametric table lists $r_{DS(ON)}$ for V_I = 3.9 V and 5.9 V, which corresponds to dropout conditions for programmed output voltages of 4 V and 6 V respectively. For other programmed values, refer to Figure 29.



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electrical characteristics, V_{I(IN)} = 4.3 V, I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 µF/CSR[†] = 1 Ω , SENSE/FB shorted to OUT (unless otherwise noted) (continued)

1.8-V regulator (TPS73HD318)

	PARAMETER	TEST CO	NDITIONS [‡]	Тj	MIN	TYP	MAX	UNIT
	Output will a se			25°C	1.746	1.8	1.854	N
Vo	Output voltage	$4.3 \text{ V} \leq \text{V}_I \leq 10 \text{ V}$		-40°C to 125°C	1.728		1.872	V
	Pass-element series	(3.5 V – V _O)/I _{O,}	V _I = 3.5 V,	25°C		0.5	1	0
	resistance	$I_0 = 750 \text{ mA},$ $V_{2SENSE} = 0 \text{ V}$	V _{2SENSE} = 0 V§	-40°C to 125°C			1.2	Ω
	Input regulation	50 $\mu A \leq I_{O} \leq$ 750 mA,	See NOTE 2	25°C		6		mV
		$I_{O} = 5 \text{ mA to } 750 \text{ mA},$	nA, See NOTE 2	25°C		14		
	Output regulation	$I_{O} = 50 \ \mu A$ to 750 mA	See NOTE 2	25°C		18		mV
	Disals sales that	f = 120 Hz,	I _O = 50 μA	25°C		51		10
	Ripple rejection	f = 120 Hz,	l _O = 500 mA	25°C		49		dB
	Output noise-spectral density	f = 120 Hz		25°C		2		mV/√Hz
		10 Hz ≤ f ≤ 100 kHz, CSR = 1 Ω	CL = 4.7 μF	25°C		274		
	Output noise voltage		C _L = 10 μF	25°C		228		μV/rms
		001(=112	CL = 100 μF	25°C		159		

[†] CSR (compensation series resistance) refers to the total series resistance, including the equivalent series resistance (ESR) of the capacitor, any series resistance added externally, and PWB trace resistance to C_I.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Pass-element series resistance measured with sense pin disconnected from output to allow output voltge to rise to full saturation.



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electrical characteristics, V_{I(IN)} = 4.3 V, I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 µF/CSR[†] = 1 Ω , SENSE/FB shorted to OUT (unless otherwise noted) (continued)

2.5-V regulator (TPS73HD325)

	PARAMETER	TEST CO	NDITIONS [‡]	Тj	MIN	TYP	MAX	UNIT
.,				25°C	2.45	2.5	2.55	
VO	Output voltage	$4.3 \text{ V} \le \text{V}_I \le 10 \text{ V}$		-40°C to 125°C	2.425		2.575	V
	Dropout voltage	I _O = 750 mA,	V _I = 3.5 V	-40°C to 125°C			800	mV
	Input regulation	50 $\mu A \leq I_{O} \leq$ 750 mA,	See NOTE 2	25°C		6		mV
		I _O = 5 mA to 750 mA,	See NOTE 2	25°C		20		mV
	Output regulation	$I_{O} = 50 \ \mu A$ to 750 mA	, See NOTE 2	25°C		25		mV
		f = 120 Hz,	I _O = 50 μA	25°C		51		5
	Ripple rejection	f = 120 Hz,	I _O = 500 mA	25°C		49		dB
	Output noise-spectral density	f = 120 Hz		25°C		2		mV/√Hz
			C _L = 4.7 μF	25°C		274		
	Output noise voltage	10 Hz \leq f \leq 100 kHz, CSR = 1 Ω	CL = 10 μF	25°C		228		μV/rms
		001(= 1 32	C _L = 100 μF	25°C		159		
V _(TO)	Trip-threshold voltage (RESET)	V _O decreasing		-40°C to 125°C	2.172			V
V _{hys}	Hysteresis voltage (RESET)			25°C		18		mV
	Low-level output voltage		1 4 4	25°C		0.17	0.4	N/
VOL	(RESET)	V _I = 2.8 V,	$I_{O(RESET)} = -1 \text{ mA}$	-40°C to 125°C			0.4	V

⁺ CSR (compensation series resistance) refers to the total series resistance, including the equivalent series resistance (ESR) of the capacitor, any series resistance added externally, and PWB trace resistance to C_L.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Pass-element series resistance measured with sense pin disconnected from output to allow output voltge to rise to full saturation.

switching characteristics

PARAMETER	TEST CONDITIONS	Тj	MIN	TYP	MAX	UNIT	
		25°C	140	200	260		
Time-out delay (RESET)	See Figure 3	-40°C to 125°C	100		300	ms	



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electrical characteristics, V_{I(IN)} = 4.3 V, I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 µF/CSR[†] = 1 Ω , SENSE/FB shorted to OUT (unless otherwise noted) (continued)

3.3-V regulator (TPS73HD301)

	PARAMETER	TEST COM	IDITIONS [‡]	ТJ	MIN	TYP	MAX	UNIT
	0			25°C		3.3		
VO	Output voltage	$4.3 \text{ V} \leq \text{V}_{I} \leq 10 \text{ V}$		-40°C to 125°C	3.23		3.37	V
		I _O = 10 mA,	V _I = 3.23 V	25°C		4.5	10	
	D	I _O = 100 mA,	V _I = 3.23 V	25°C		44	100	
	Dropout voltage			25°C		353	750	mV
		I _O = 750 mA,	V _I = 3.23 V	-40°C to 125°C			800	
	Pass-element series	(3.23 V – V _O)/I _{O.}	VI = 3.23 V,	25°C		0.44	1	
	resistance	l _O = 750 mA		-40°C to 125°C			1.07	Ω
	Input regulation	$50 \ \mu A \le I_O \le 750 \ mA$,	See NOTE 2	25°C		6		mV
		$I_{O} = 5 \text{ mA to } 750 \text{ mA},$	See NOTE 2	25°C		30		mV
	Output regulation	$I_{O} = 50 \ \mu A$ to 750 mA,	See NOTE 2	25°C		37		mV
		f = 120 Hz,	l _O = 50 μA	25°C		51		
	Ripple rejection	f = 120 Hz,	I _O = 500 mA	25°C		49		dB
	Output noise-spectral density	f = 120 Hz		25°C		2		mV/√Hz
			C _L = 4.7 μF	25°C		274		
	Output noise voltage	10 Hz ≤ f ≤ 100 kHz, CSR = 1 Ω	C _L = 10 μF	25°C		228		μV/rms
		CSR = 1 12	C _L = 100 μF	25°C		159		
V(TO)	Trip-threshold voltage (RESET)	V _O decreasing		-40°C to 125°C	2.868			V
V _{hys}	Hysteresis voltage (RESET)			25°C		18		mV
	Low-level output voltage			25°C		0.17	0.4	
VOL	(RESET)	V _I = 2.8 V,	IO(RESET) = -1 mA	-40°C to 125°C			0.4	V

⁺ CSR (compensation series resistance) refers to the total series resistance, including the equivalent series resistance (ESR) of the capacitor, any series resistance added externally, and PWB trace resistance to C_L.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

switching characteristics

PARAMETER	TEST CONDITIONS	ТJ	MIN	TYP	MAX	UNIT	
		25°C	140	200	260		
Time-out delay (RESET)	See Figure 3	-40°C to 125°C	100		300	ms	



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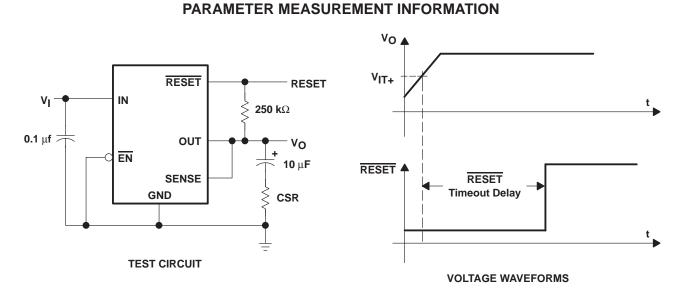


Figure 1. Test Circuit and Voltage Waveforms

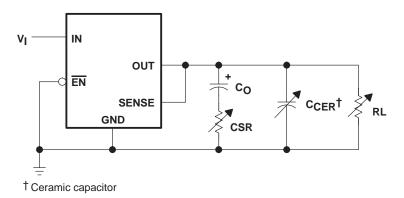


Figure 2. Test Circuit for Typical Regions of Stability (Refer to Figures 29 through 32)



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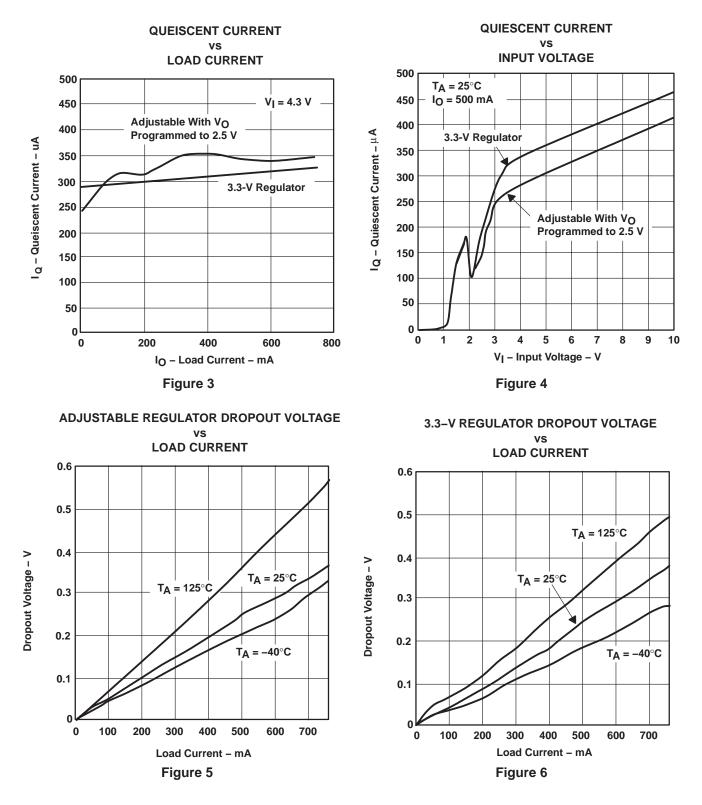
TYPICAL CHARACTERISTICS

Table of Graphs

		vs Load current	5	
IQ	Quiescent current		vs Input voltage	6
		Adjustable regulator	vs Load current	7
V _{DO}	Dropout voltage	3.3-V regulator	vs Load current	8
ΔVDO	Change in dropout voltage		vs Free-air temperature	9
VDO	Dropout voltage		vs Output current	10
ΔVO	Change in output voltage		vs Free-air temperature	11
Vo	Output voltage		vs Input voltage	12
	Line regulation		13	
Vo	Output voltage	vs Output current	14, 15	
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		Adjustable regulator		17
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		Adjustable regulator		19
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	Output spectral noise density	vs Frequency	22	
			vs Output current	23
		Adjustable regulator	vs Added ceramic capacitance	24
	Componentian environ registering (CSD)		vs Output current	25
	Compensation series resistance (CSR)	3.3-V regulator	vs Output current	26
		Adjustable regulator	vs Added ceramic capacitance	27
		vs Added ceramic capacitance	28	
^r DS(on)	Pass-element resistance		vs Input voltage	29
VI	Minimum input voltage for valid RESET	vs Free-air temperature	30	
V _{IT-}	Negative-going reset threshold		vs Free-air temperature	31
IOL(RESET)	RESET output current	3.3-V regulato	vs Input voltage	32
t _d	Reset time delay		vs Free-air temperature	33
t _d	Distribution for reset delay		34	

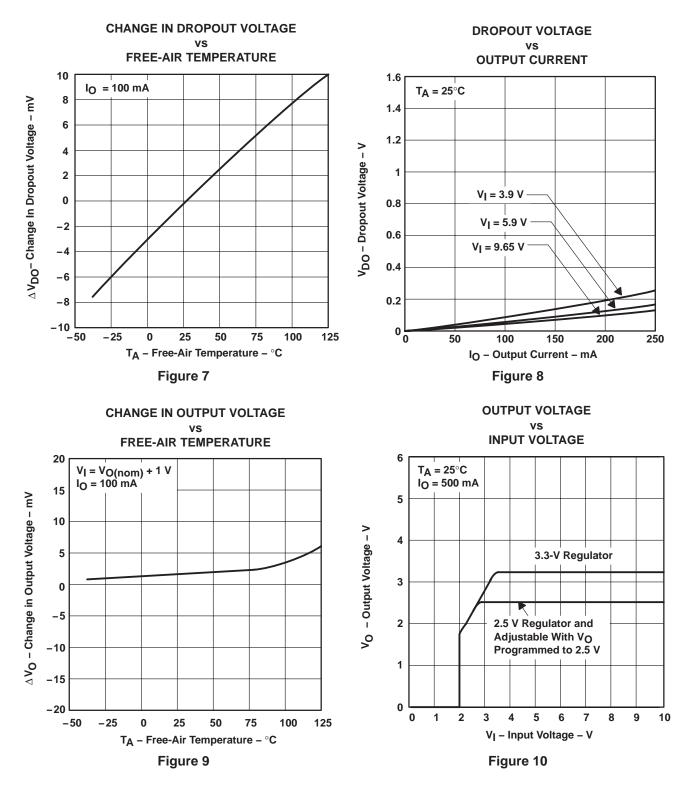


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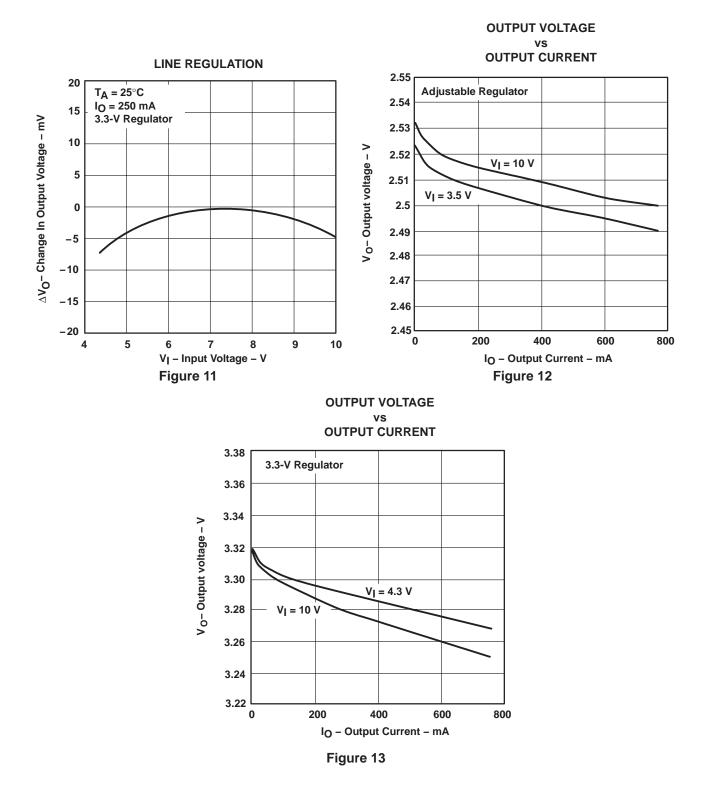


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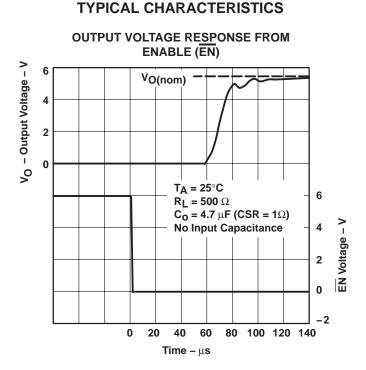


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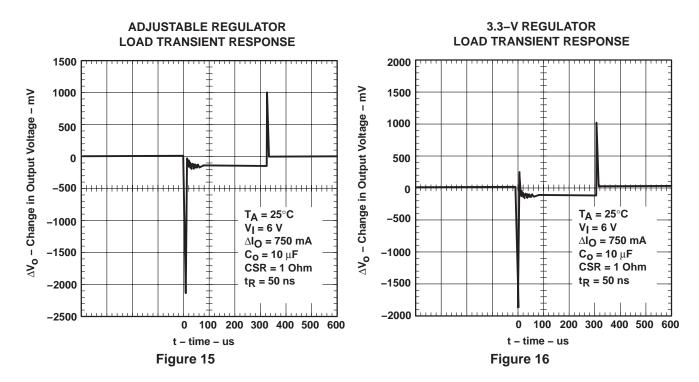




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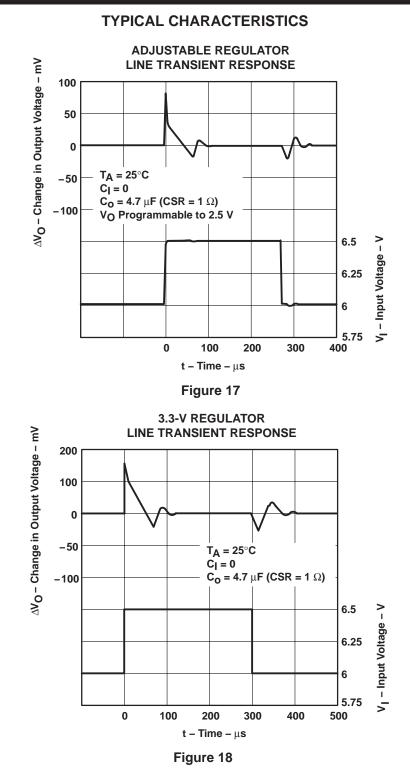






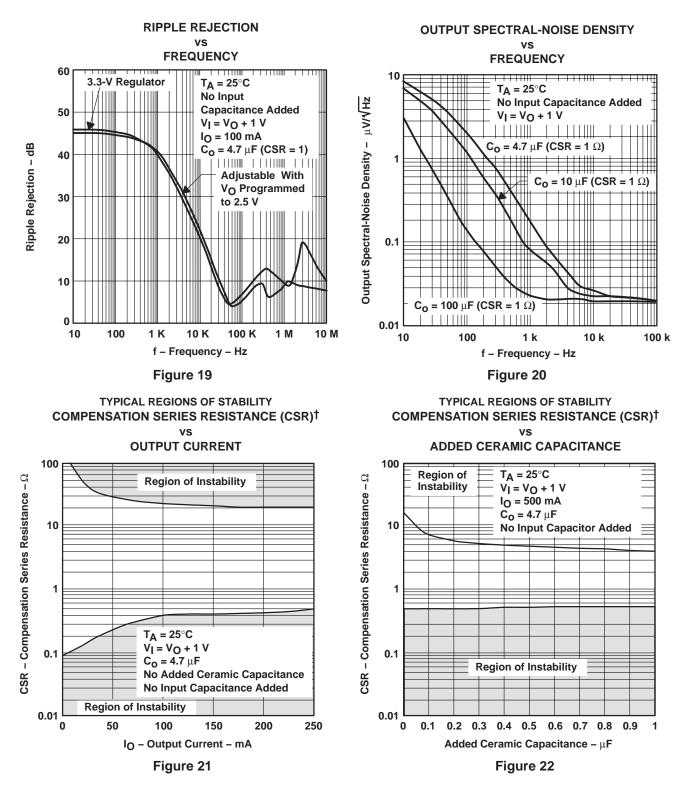


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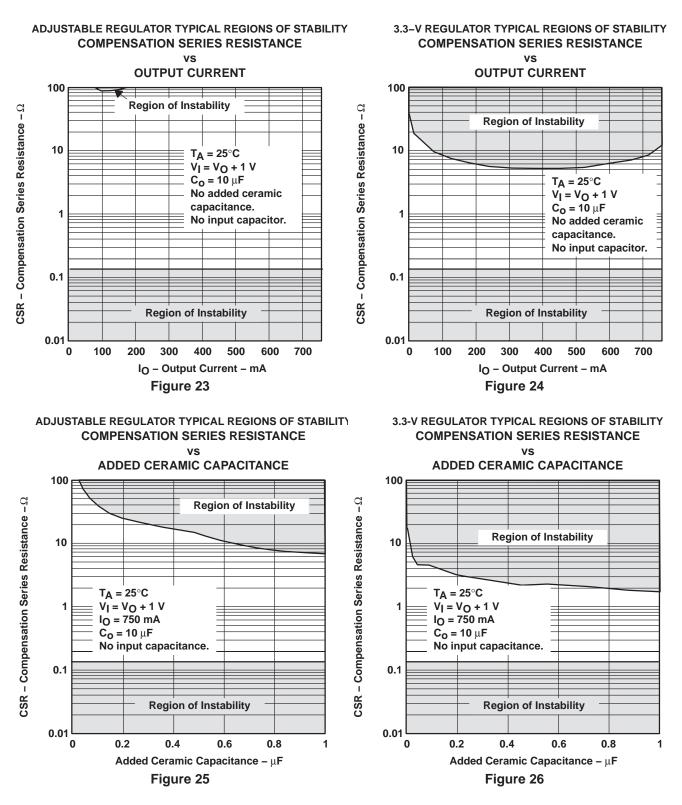


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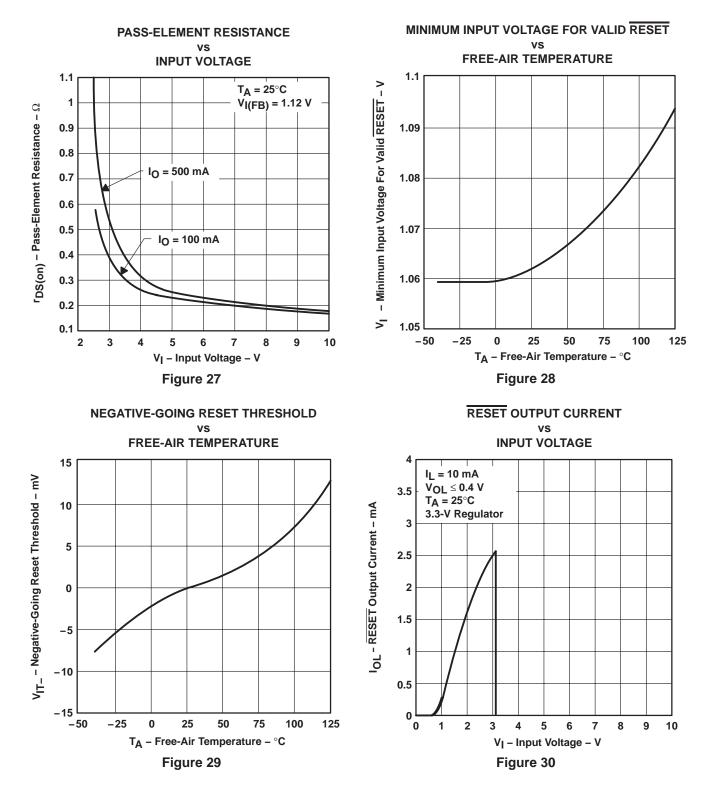


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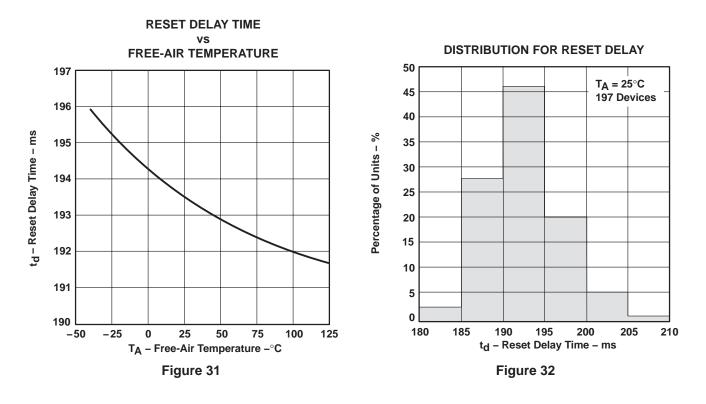
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TYPICAL CHARACTERISTICS



THERMAL INFORMATION

The TPS73HD3xx is packaged in a high-power dissipation downset lead frame for optimal power handling. with proper heat dissipation techniques, the full power soutput of these devices can be safely handled over the full temperture range. The Texas Instruments technical brief, *PowerPAD Thermally Enhanced Package* (literature number SLMA002), goes into considerable detail into techniques for properly mounting this type of package for maximum thermal performance. A thermal conduction plane of approximately 3" y 3" will give a power dissipatio level of 4.5 W.

Power dissipation within the device can be calculated with the following equation:

$$P_D = P_{IN} - P_{OUT} = V_I (I_{O1} + I_{O2}) - (V_{O1} \times I_{O1} + V_{O2} \times I_{O2})$$



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APPLICATION INFORMATION

thermal considerations

DISSIPATION RATING TABLE							
PACKAGE	AIR FLOW (CFM)	T _A < 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING		
pwpt	0	2.9 W	23.5 mW/°C	1.9 W	1.5 W		
PWP‡	300	4.3 W	34.6 mW/°C	2.8 W	2.2 W		
24426	0	3 W	23.8 mW/°C	1.9 W	1.5 W		
PWP§	300	7.2 W	57.9 mW/°C	4.6 W	3.8 W		

[†]This parameter is measured with the recommended copper heat sink pattern on a 1-layer PCB, 5-in \times 5-in PCB, 1 oz. copper, 2-in \times 2-in coverage (4 in²).

[‡] This parameter is measured with the recommended copper heat sink pattern on an 8-layer PCB, 1.5-in × 2-in PCB, 1 oz. copper with layers 1, 2, 4, 5, 7, and 8 at 5% coverage (0.9 in²) and layers 3 and 6 at 100% coverage (6 in²).

The maximum ambient temperature depends on the heatsinking ability of the PCB system. Using the 0 CFM and 300 CFM data from the dissipation rating table, the derating factor for the PWP package with 6.9 in² of copper area on a multilayer PCB is 24 mW/°C and 58 mW/°C respectively. Converting this to Θ_{JA} :

$$\Theta_{JA} = \frac{1}{Derating}$$

For 0 CFM : = $\frac{1}{0.0235}$ For 300 CFM : = $\frac{1}{0.0579}$ = 42.6°C/W = 17.3°C/W

Given Θ_{JA} , the maximum allowable junction temperature, and the total internal dissipation, the maximum ambient temperature can be calculated with the following equation. The maximum recommended junction temperature for the TPS73HD3xx is 150 °C.

$$\mathsf{T}_{\mathsf{A}} \mathsf{Max} = \mathsf{T}_{\mathsf{J}} \mathsf{Max} - \left(\Theta_{\mathsf{J}\mathsf{A}} \times \mathsf{P}_{\mathsf{D}} \right)$$

The maximum power dissipation limit is determined using the following equation:

$$T_{D(max)} = \frac{T_{J}max - T_{A}}{R_{\theta JA}}$$

Where:

T_Jmax is the maximum allowable junction temperature

 $R_{\theta JA}$ is the thermal resistance junction-to-free-air for the package (i.e., 285°C/W for the 5-terminal SOT-23 package.

T_A is the free-air temperautre

The regulator dissipation is calculated using:

$$\mathsf{P}_{\mathsf{D}} = \left(\mathsf{V}_{\mathsf{I}} - \mathsf{V}_{\mathsf{O}}\right) \times \mathsf{1}_{\mathsf{O}}$$

Power dissipation resulting from quiescent current is negligible.



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APPLICATION INFORMATION

Capitalizing upon the features of the TPS73xx family (low-dropout voltage, low quiescent current, power-saving shutdown mode, and a supply-voltage supervisor) and the power-dissipation properties of the TSSOP PowerPAD package has enabled the integration of the TPS73HD3xx dual LDO regulator with high output current for use in DSP and other multiple voltage applications. Figure 35 shows a typical dual-voltage DSP application.

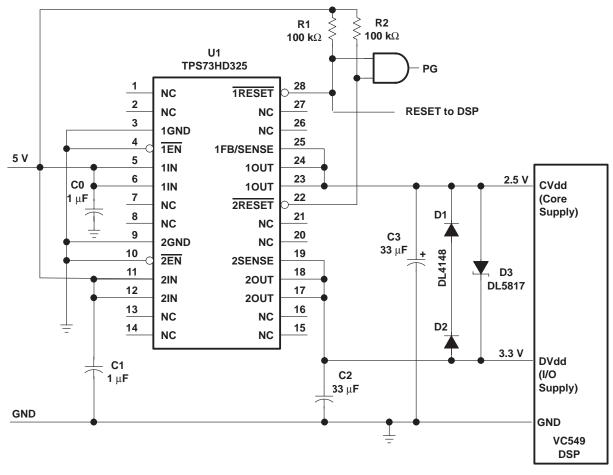


Figure 33. Dual-Voltage DSP Application

DSP power requirements include very high transient currents that must be considered in the initial design. This design uses higher-valued output capacitors to handle the large transient currents. Details of this type of design are shown in the application report, *Designing Power Supplies for TMS320VC549 DSP Systems.*

minimum load requirements

The TPS73HD3xx is stable even at zero load; no minimum load is required for operation.



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APPLICATION INFORMATION

SENSE connection

The SENSE terminal of fixed-output devices must be connected to the regulator output for proper functioning of the regulator. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit (remote sense) to improve performance at that point. Internally, SENSE connects to a high-impedance wide-bandwidth amplifier through a resistor-divider network, and noise pickup feeds through to the regulator output. It is essential to route the SENSE connection in such a way as to minimize/avoid noise pickup. Adding an RC network between SENSE and OUT to filter noise is not recommended because it can cause the regulator to oscillate.

external capacitor requirements

An input capacitor is not required; however, a ceramic bypass capacitor (0.047 pF to 0.1 μ F) improves load transient response and noise rejection when the TPS73HD3xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

As with most LDO regulators, the TPS73HD3xx requires an output capacitor for stability. A low-ESR 10- μ F solid-tantalum capacitor connected from the regulator output to ground is sufficient to ensure stability over the full load range (see Figure 44). Adding high-frequency ceramic or film capacitors (such as power-supply bypass capacitors for digital or analog ICs) can cause the regulator to become unstable unless the ESR of the tantalum capacitor is less than 1.2 Ω over temperature. Capacitors with published ESR specifications such as the AVX TPSD106M035R0300 and the Sprague 593D106X0035D2W work well because the maximum ESR at 25°C is 300 m Ω (typically, the ESR in solid-tantalum capacitors increases by a factor of 2 or less when the temperature drops from 25°C to -40° C). Where component height and/or mounting area is a problem, physically smaller, 10- μ F devices can be screened for ESR. Figures 23 through 28 show the stable regions of operation using different values of output capacitance with various values of ceramic load capacitance.

Due to the reduced stability range available when using output capacitors smaller than 10 μ F, capacitors in this range are not recommended. Larger capacitors provide a wider range of stability and better load transient response. Because capacitor minimum ESR is seldom if ever specified, it may be necessary to add a 0.5- Ω to 1- Ω resistor in series with the capacitor and limit ESR to 1.5 Ω maximum. As shown in the CSR graphs (Figures 23 through 28), minimum ESR is not a problem when using 10- μ F or larger output capacitors.

Below is a partial listing of surface-mount capacitors usable with the TPS73HD3xx. This information, along with the CSR graphs, is included to assist in selection of suitable capacitance for the user's application. When necessary to achieve low height requirements along with high output current and/or high ceramic load capacitance, several higher ESR capacitors can be used in parallel to meet the guidelines above.



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APPLICATION INFORMATION

external capacitor requirements (continued)

All load and temperature conditions with up to 1 μ F of added ceramic load capacitance:								
N) †								
2								
3								
3								
3								
v) †								
6								
2								
2								
3								
//)†								
7								
7								
6								
4								
4								
5								

[†] Size is in mm. ESR is maximum resistance at 100 kHz and $T_A = 25^{\circ}C$. Listings are sorted by height.



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APPLICATION INFORMATION

programming the adjustable LDO regulator output

Programming the adjustable regulator is done using an external resistor divider as shown in Figure 44. The equation governing the output voltage is:

$$V_{O} = V_{ref} \times \left(1 + \frac{R1}{R2}\right)$$

Where

V_{ref} = reference voltage, 1.182 V typ

Resistors R1 and R2 should be chosen for approximately 7- μ A divider current. A recommended value for R2 is 169 k Ω with R1 adjusted for the desired output voltage. Smaller resistors can be used, but offer no inherent advantage and consume more power. Larger values of R1 and R2 should be avoided as leakage currents at FB will introduce an error. Solving for R1 yields a more useful equation for choosing the appropriate resistance:

$$R1 = \left(\frac{V_{O}}{V_{ref}} - 1\right) \times R2$$

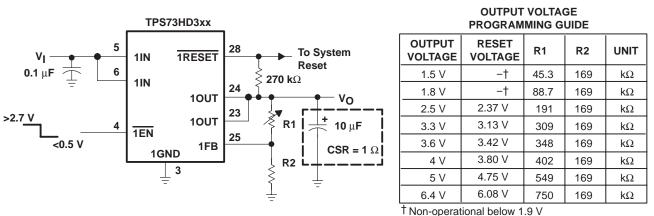


Figure 34. TPS7301 Adjustable LDO Regulator Programming



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APPLICATION INFORMATION

undervoltage supervisor function

The RESET outputs of the TPS73HD3xx initiate a reset in microcomputer and microprocessor systems in the event of an undervoltage condition. An internal comparator in the TPS73HD3xx monitors the output voltage of the regulator to detect the undervoltage condition. When that occurs, the RESET output transistor turns on, taking the RESET signal low.

At programmed output voltages below 1.9 V (on the adjustable regulator only) and on the 1.8 V regulator the reset function becomes unusable. With a minimum output voltage requirement for a valid RESET signal (over temperature) being 1.9 V, RESET will not operate reliably in this range.

On power up, the output voltage tracks the input voltage. The $\overline{\text{RESET}}$ output becomes active (low) as V_I approaches the minimum required for a valid $\overline{\text{RESET}}$ signal (specified at 1.5 V for 25°C and 1.9 V over full recommended operating temperature range). When the output voltage reaches the appropriate positive-going input threshold (V_{IT+}), a 200-ms (typical) timeout period begins during which the $\overline{\text{RESET}}$ output remains low. Once the timeout has expired, the $\overline{\text{RESET}}$ output becomes inactive. Since the $\overline{\text{RESET}}$ output is an open-drain NMOS, a pullup resistor should be used to ensure that a logic-high signal is indicated.

The supply-voltage-supervisor function is also activated during power down. As the input voltage decays and after the dropout voltage is reached, the output voltage tracks linearly with the decaying input voltage. When the output voltage drops below the specified negative-going input threshold (V_{IT-} — see electrical characteristics tables), the RESET output becomes active (low). It is important to note that if the input voltage decays below the minimum required for a valid RESET, the RESET is undefined.

Since the circuit is monitoring the regulator output voltage, the \overline{RESET} output can also be triggered by disabling the regulator or by any fault condition that causes the output to drop below V_{IT}. Examples of fault conditions include a short circuit on the output and a low input voltage. Once the output voltage is reestablished, either by reenabling the regulator or removing the fault condition, then the internal timer is initiated, which holds the \overline{RESET} signal active during the 200-ms (typical) timeout period.

Transient loads or line pulses can also cause a reset to occur if proper care is not taken in selecting the input and output capacitors. Load transients that are faster than 5 μ s can cause a reset if high-ESR output capacitors (greater than approximately 7 Ω) are used. A 1- μ s transient causes a reset when using an output capacitor with greater than 3.5 Ω of ESR. Note that the output-voltage spike during the transient can drop well below the reset threshold and still not trip if the transient duration is short. A 1- μ s transient must drop at least 500 mV below the threshold before tripping the reset circuit. A 2- μ s transient trips RESET at just 400 mV below the threshold. Lower-ESR output capacitors help by reducing the drop in output voltage during a transient and should be used when fast transients are expected.

NOTE: $V_{IT+} = V_{IT-} + Hysteresis$

output noise

The TPS73HD3xx has very low output noise, with a spectral noise density < $2 \mu V / \sqrt{Hz}$. This is important when noise-susceptible systems, such as audio amplifiers, are powered by the regulator.



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APPLICATION INFORMATION

regulator protection

The TPS73HD3xx PMOS-pass transistors have built-in back diodes that safely conduct reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage is anticipated, external limiting might be appropriate.

The TPS73HD3xx also features internal current limiting and thermal protection. During normal operation, the TPS73HD3xx limits output current to approximately 1 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 165°C, thermal-protection circuitry shuts it down. Once the device has cooled, regulator operation resumes.



W TEXAS

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS73HD301PWP	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD301PWPG4	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD301PWPR	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD301PWPRG4	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD318PWP	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD318PWPG4	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD318PWPR	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD318PWPRG4	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD325PWP	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD325PWPG4	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD325PWPR	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
TPS73HD325PWPRG4	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

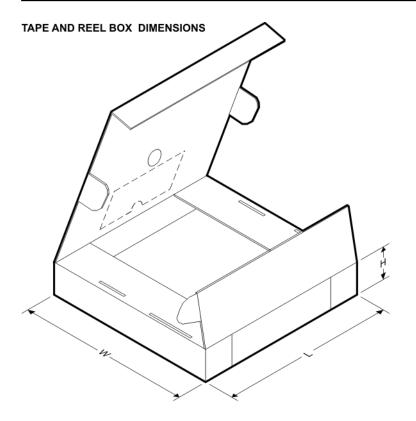


*/	*All dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	TPS73HD301PWPR	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
	TPS73HD318PWPR	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
	TPS73HD325PWPR	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

11-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS73HD301PWPR	HTSSOP	PWP	28	2000	346.0	346.0	33.0
TPS73HD318PWPR	HTSSOP	PWP	28	2000	346.0	346.0	33.0
TPS73HD325PWPR	HTSSOP	PWP	28	2000	346.0	346.0	33.0



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



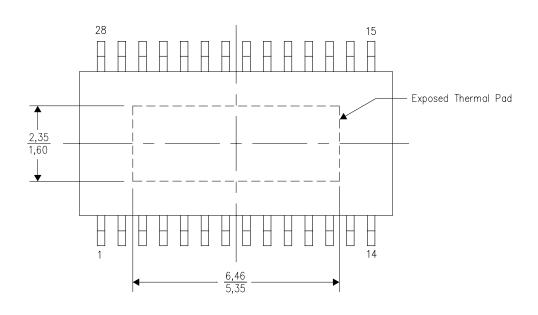


THERMAL INFORMATION

This PowerPAD[™] package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



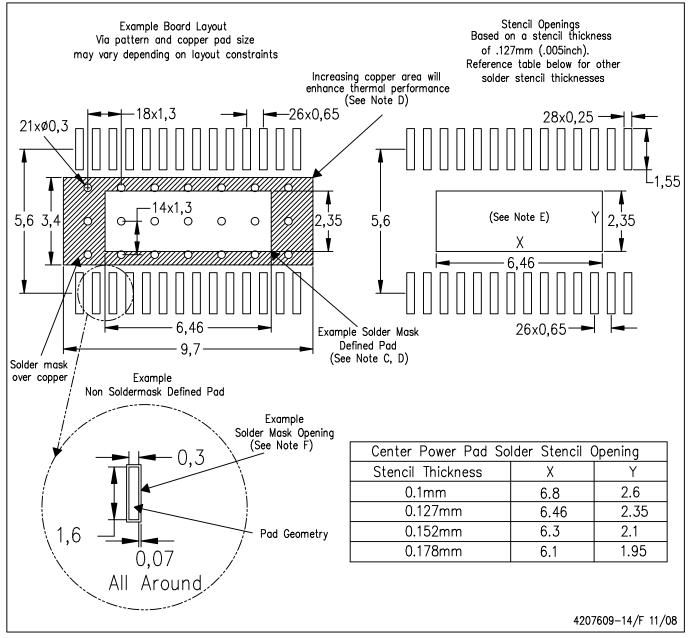
Top View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

LAND PATTERN

PWP (R-PDSO-G28) PowerPAD™



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads. PowerPAD is a trademark of Texas Instruments.



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